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Semiconductor science and technology:

Semiconductor Science and Authors: Jenner, C.; Corbin, E.; Adderley, B.M.; Jaros, M. Electrical characterization of deep levels existing in Mg-Si- and Mg-P-Si

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Deep levels in semiconductors. (book, 1982)

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Deep-level transient spectroscopy - wikipedia,

Deep-level transient This voltage pulse reduces the electric field in the space charge region and allows free carriers from the semiconductor bulk to penetrate

Deep level recombination in semiconductors

Deep Level Recombination in Semiconductors M. Jaros, "A case for large Auger recombination cross sections associated with deep centers in semiconductors

Optical cross sections associated with deep levels

Title: Optical cross sections associated with deep levels in semiconductors. II. Comparison of theory with experiment: Authors: Jaros, M.; Banks, P. W.

Deep level saturation spectroscopy

We review the Deep Level Saturation Spectroscopy (DLSS) as the nonlinear method to study the deep local defects in semiconductors. The

D.j. wolford - google scholar citations

Theory of substitutional deep traps in covalent semiconductors. HP Hjalmarson, JA Bradley, MA Gell, D Ninno, M Jaros. *Journal of Vacuum Science* DJ Wolford, E

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Deep-level trap - wikipedia, the free

Deep-level traps or deep-level defects are a generally undesirable type of electronic defect in semiconductors. They are "deep" in the sense that the energy required

Monte carlo simulation of carrier capture at deep

This work provides a direct way to include multiphonon capture at deep levels Monte Carlo Simulation of Carrier Capture at Deep E. Meijer and M. Jaros,

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Deep Impurity Levels in Semiconductors, Semiconductor While specific deep levels were explained J. A. Bradley, M. A. Grell, D. Ninno, and M. Jaros, J. Vac

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Deep donor levels (dx centers) in iii v

deep levels associated with donors in in order to determine the usefulness of III V semiconductors for heterojunction Deep donor levels

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Growth parameter optimization for fast quantum dot SESAMs D. J. H "Multiphonon-assisted tunneling through deep levels: Jaros, M. M. A. Cusack, P. R

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Non-radiative transitions in semiconductors -

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Oscillations in semiconductors due to deep levels

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